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Bib Data Sheet

CONFIRMATION NO. 7221

<b>SERIAL NUMBER</b> 10/039.196	<b>FILING DATE</b> 01/02/2002 <b>RULE</b>	<b>CLASS</b> <del>417</del> 428	<b>GROUP ART UNIT</b> <del>1765</del> 1772	<b>ATTORNEY DOCKET NO.</b> MEMC 00-1400 (2806.1)
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## APPLICANTS

Robert J. Falster, London, UNITED KINGDOM;  
Vladimir V. Voronkov, Merano, ITALY;  
Paolo Mutti, Milan, ITALY;  
Fancesco Bonoli, Novara, ITALY;

## \*\* CONTINUING DATA \*\*\*\*\*

THIS APPLN CLAIMS BENEFIT OF 60/259,362 01/02/2001

yes GR

## \*\* FOREIGN APPLICATIONS \*\*\*\*\*

none GR

## IF REQUIRED, FOREIGN FILING LICENSE GRANTED

\*\* 01/28/2002

Foreign Priority claimed <input type="checkbox"/> yes <input checked="" type="checkbox"/> no	STATE OR COUNTRY UNITED KINGDOM	SHEETS DRAWING 17	TOTAL CLAIMS 59	INDEPENDENT CLAIMS 3
35 USC 119 (a-d) conditions met <input type="checkbox"/> yes <input checked="" type="checkbox"/> no <input type="checkbox"/> Met after Allowance				
Verified and Acknowledged Examiner's Signature: <i>[Signature]</i> Initials: <i>[Initials]</i>				

## ADDRESS

000321

## TITLE

Process for preparing single crystal silicon having improved gate oxide integrity

<b>FILING FEE RECEIVED</b> 2356	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees ( Filing ) <input type="checkbox"/> 1.17 Fees ( Processing Ext. of time ) <input type="checkbox"/> 1.18 Fees ( Issue ) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit _____
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